

L Number	Hits	Search Text	DB	Time stamp
1	1650	349/113	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:10
2	1329	349/138	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:11
3	2268	349/42	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:11
4	1523	349/43	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:11
5	1409	349/153	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:11
6	2	(insult\$6 and (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation nearl0 (reflect\$4 metal pixel)) and 349/113	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:11
7	0	(insult\$6 with (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and 349/113	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:12
8	2	(insult\$6 and (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation nearl0 (reflect\$4 metal pixel)) and 349/138	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:12
9	3	(insult\$6 and (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation nearl0 (reflect\$4 metal pixel)) and 349/42	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:12
10	8	(insult\$6 and (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation nearl0 (reflect\$4 metal pixel)) and 349/43	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:13
11	0	(insult\$6 and (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation nearl0 (reflect\$4 metal pixel)) and 349/153	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2004/06/04 14:13
-	1	6344888.pn.	USPAT	2002/11/05 09:54
-	46263	insulat\$6 and moisture	USPAT; JPO	2002/09/10 10:18
-	10402	insulat\$6 with moisture	USPAT; JPO	2002/09/10 10:18
-	43	(insulat\$6 with moisture) and 349/\$.cccls.	USPAT; JPO	2003/05/15 16:47
-	24	(insult\$6 with (silicon adj (nitride or oxide))) and laminat\$5	USPAT; JPO	2002/10/15 14:31
-	34	(insult\$6 with (silicon adj (nitride or oxide))) and (laminat\$5 or stack)	USPAT; JPO	2003/05/15 16:47
-	3883	((insult\$6 or dielectric) same (silicon adj (nitride or oxide))) and (laminat\$5 or stack)	USPAT; JPO	2002/10/15 14:34
-	3050	((insult\$6 or dielectric) with (silicon adj (nitride or oxide))) and (laminat\$5 or stack)	USPAT; JPO	2002/10/15 14:34

-	36	((insult\$6 or dielectric) near (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and periphery and ((semiconductor or silicon) adj substrate)	USPAT; JPO	2002/10/15 14:40
-	51	((insult\$6 or dielectric) near (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and periphery	USPAT; JPO	2002/10/15 14:39
-	375	((insult\$6 or dielectric) near (silicon adj (nitride or oxide))) and (laminat\$5 or stack)	USPAT; JPO	2002/10/15 15:11
-	14	((insult\$6 or dielectric) near (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (liquid adj crystal)	USPAT; JPO	2002/10/15 15:12
-	41	("3862360"   "3910681"   "4024626"   "4040727"   "4073571"   "4103297"   "4185894"   "4191452"   "4239346"   "4382658"   "4431271"   "4470060"   "4602850"   "4822144"   "4839707"   "4856019"   "5007710"   "5056895"   "5159476"   "5218472"   "5254202"   "5365355"   "5395662"   "5461501"   "5467216"   "5473448"   "5497025"   "5523862"   "5570213"   "5648860"   "5680231"   "5706067"   "5760853"   "5760981"   "5764324"   "5798805"   "5828493"   "5834103"   "5838715"   "5889570"   "5978056").PN.	USPAT	2002/10/15 15:13
-	1	6124912.pn.	USPAT	2002/11/05 09:54
-	63	(insulat\$6 with moisture) and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/15 16:47
-	68	(insult\$6 with (silicon adj (nitride or oxide))) and (laminat\$5 or stack)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/04 14:12
-	4	(insult\$6 with (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation near10 (reflect\$4 metal pixel))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/20 13:31
-	46	(insult\$6 and (silicon adj (nitride or oxide))) and (laminat\$5 or stack)and (passivation near10 (reflect\$4 metal pixel))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/06/04 14:12